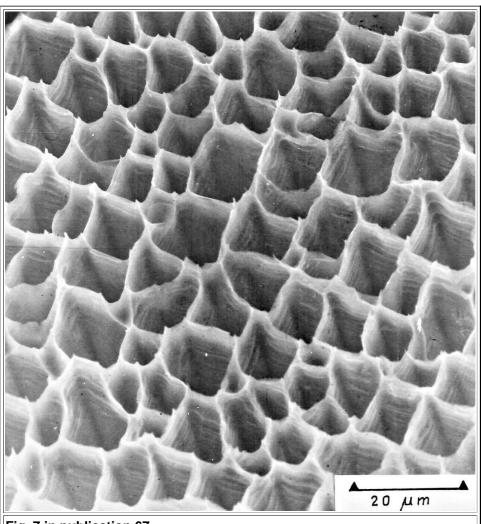
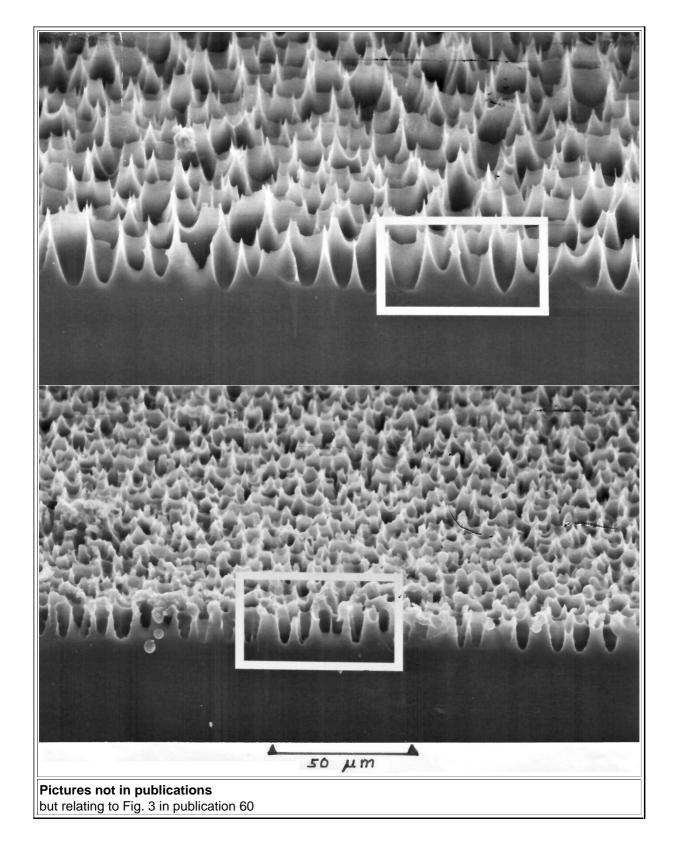
## Pictures to: 5. Siemens Research Munich

## **5.3 Pore Etching**

Most old pictures have not survived. Here is what I still have.



**Fig. 7 in publication 67**Microstructure of n-type Si after prolonged etching with  $I < I_{PSL}$ 



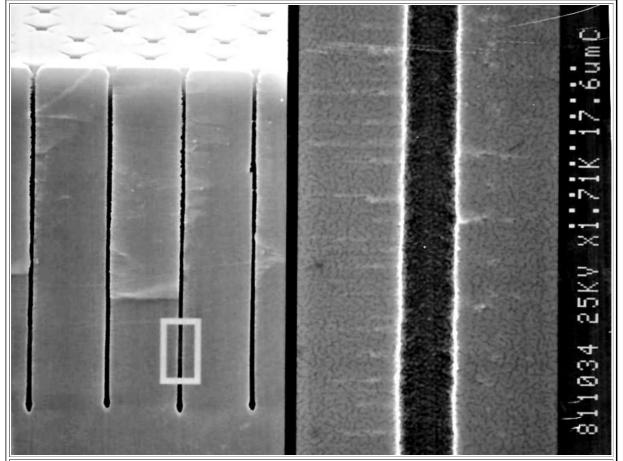
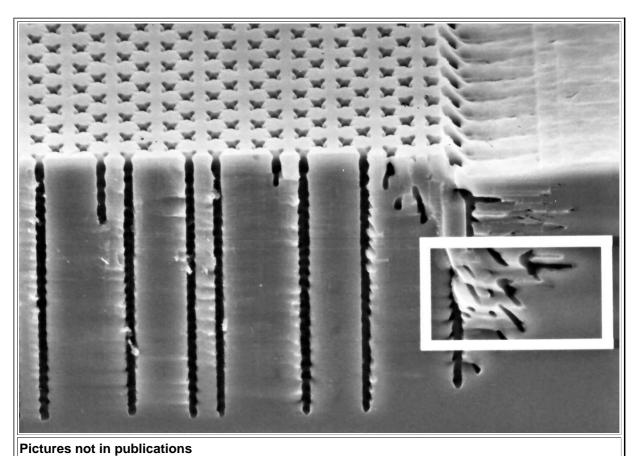


Fig 9 in publication 67 and relating to Fig 9 in 60

Fig. 9. SEM micrograph (cross section, 0°) of electrochemically etched trenches with high aspect ratio. (B2 sample, 10V, 30 min,330 pA/trench; all three samples: photocurrent adjusted by back sideillumination, PSL removed by 10s in 10 w/o KOH.)

The picture rom the full paper (ref, 60) follows



but obviously related.